



### **40V P-CHANNEL ENHANCEMENT MODE MOSFET**

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max (A) T <sub>A</sub> = +25°C
40\/	25mΩ @ V <sub>GS</sub> = -10V	-8.0A
-40V	45mΩ @ V <sub>GS</sub> = -4.5V	-6.0A

### **Features and Benefits**

- Low R<sub>DS(ON)</sub> Minimizes Conduction Losses
- Fast Switching Speed Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

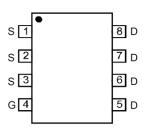
- Motor Control
- Backlighting
- DC-DC Converters
- Printer Equipment

### **Mechanical Data**

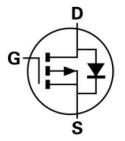
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0 (Note 1)
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.074 grams (Approximate)







Pin-Out Top View



Internal Schematic

### Ordering Information (Note 5)

Part Number	Case	Packaging
DMP4025LSSQ-13	SO-8	2,500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



Oll = Manufacturer's Marking
P4025LS = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 16 = 2016)
WW = Week (01 - 53)



### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			$V_{DSS}$	-40	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current V <sub>GS</sub> = -1		(Note 7)		-8.0	
	$V_{GS} = -10V$	T <sub>A</sub> = +70°C (Note 7)	I <sub>D</sub>	-6.9	
		(Note 6)		-6.0	Α
Pulsed Drain Current	$V_{GS} = -10V$	(Note 8)	I <sub>DM</sub>	-30	
Continuous Source Current (Body Diode)		(Note 8)	Is	-8.0	
Pulsed Source Current (Body Diode) (N		(Note 8)	I <sub>SM</sub>	-30	

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	Б	1.52	W	
Power Dissipation	(Note 7)		2.4	VV	
Thermal Resistance, Junction to Ambient	(Note 6)	82			
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	52	°C/W	
Thermal Resistance, Junction to Lead (Note 9)		$R_{ heta JL}$	48.85		
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Co	ondition
OFF CHARACTERISTICS (Note 10)							
Drain-Source Breakdown Voltage	$BV_{DSS}$	-40	_	_	V	$I_D = -250\mu A, V_{GS} = 0V$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	-1.0	μΑ	V <sub>DS</sub> = -40V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS}$	= 0V
ON CHARACTERISTICS (Note 10)							
Gate Threshold Voltage	$V_{GS(TH)}$	-0.8	-1.3	-1.8	V	$I_D = -250 \mu A, V_{DS}$	= V <sub>GS</sub>
Static Drain-Source On-Resistance			18	25	0	$V_{GS} = -10V, I_D = -3A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	30	45	mΩ	$V_{GS} = -4.5V, I_{D} =$	-3A
Forward Transconductance	<b>g</b> FS		16.6	_	S	$V_{DS} = -5V, I_{D} = -3$	3A
Diode Forward Voltage	$V_{SD}$		-0.7	-1.0	V	$I_S = -1A, V_{GS} = 0$	V
DYNAMIC CHARACTERISTICS (Note 11)							
Input Capacitance	C <sub>ISS</sub>		1,640	_		$V_{DS} = -20V$ , $V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss		179	_	pF		
Reverse Transfer Capacitance	C <sub>RSS</sub>	_	128	_			
Gate Resistance	Rg	_	6.43	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	$Q_{G}$	_	14.0	_		$V_{GS} = -4.5V$	-4.5V
Total Gate Charge	$Q_{G}$	_	33.7	_	nC	$V_{\text{GS}} = -10V$ $V_{\text{DS}} = -20V$ $I_{\text{D}} = -3A$	$V_{DS} = -20V$
Gate-Source Charge	$Q_GS$	_	5.5	_	IIC		$I_D = -3A$
Gate-Drain Charge	$Q_{GD}$	_	7.3	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.9	_		V <sub>DD</sub> = -20V, V <sub>GS</sub> = -10V I <sub>D</sub> = -3A	
Turn-On Rise Time	t <sub>R</sub>	_	14.7	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	53.7	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	30.9	_			

6. For a device surface mounted on minimum recommended FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is Notes: measured when operating in a steady-state condition.

<sup>7.</sup> Same as Note (6), except the device is surface mounted on 25mm x 25mm x 1.6mm FR4 PCB.

8. Repetitive rating on 25mm X 25mm FR4 PCB, D=0.02, pulse width 300µs – pulse width by maximum junction temperature.

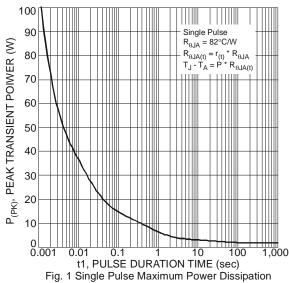
9. Thermal resistance from junction to solder-point (at the end of the drain lead).

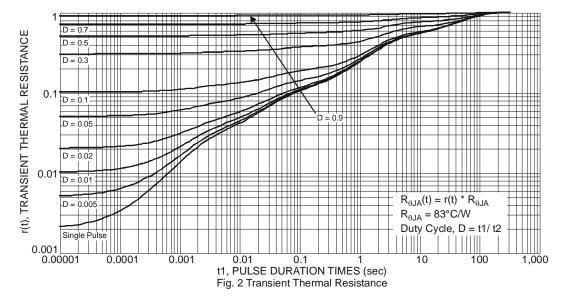
<sup>10.</sup> Short duration pulse test used to minimize self-heating effect.

<sup>11.</sup> Guaranteed by design. Not subject to production testing.



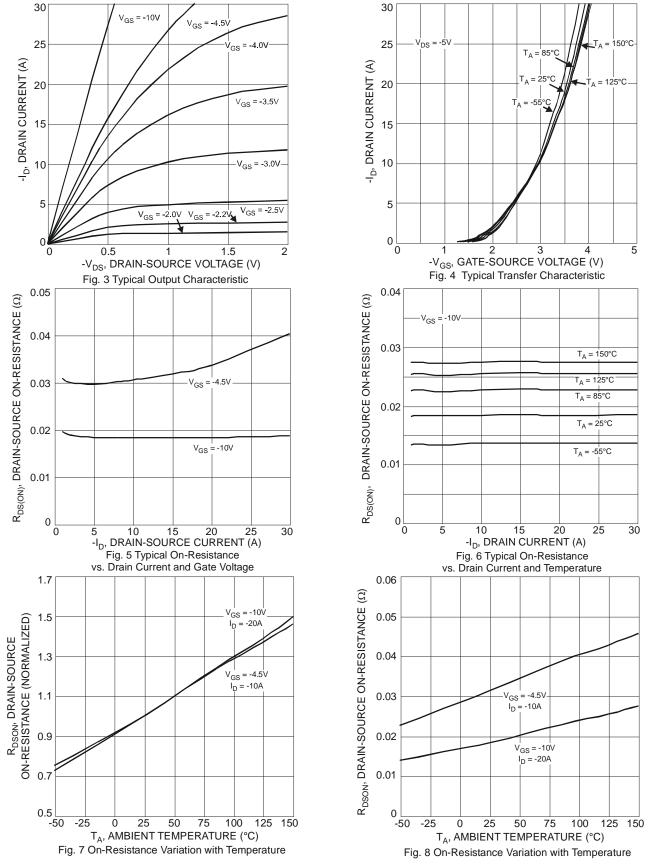
### **Thermal Characteristics**



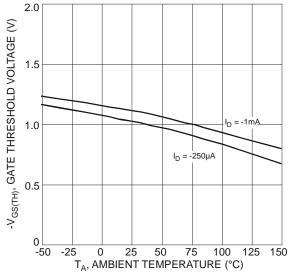


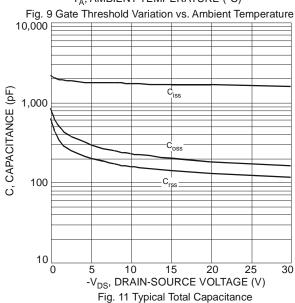


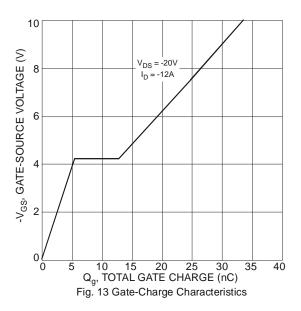
# **Typical Characteristics**

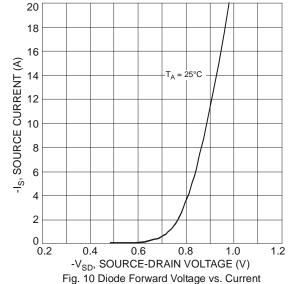


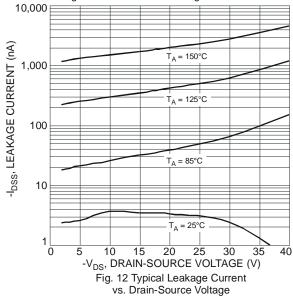










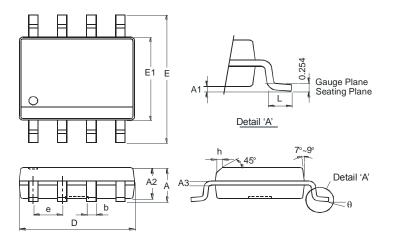




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

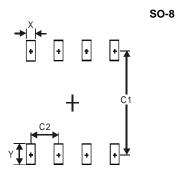
**SO-8** 



	SO-8				
Dim	Min	Max			
Α	_	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
Е	5.90	6.10			
E1	3.85	3.95			
е	<b>e</b> 1.27 Typ				
h	1	0.35			
L	0.62	0.82			
θ	0°	8°			
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

May 2016



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